DISCRETE SEMICONDUCTORS

DATA SHEET



BA682; BA683 Band-switching diodes

Product specification Supersedes data of April 1992 1996 Mar 13





Band-switching diodes

BA682; BA683

FEATURES

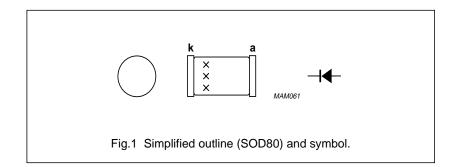
- Continuous reverse voltage: max. 35 V
- Continuous forward current: max. 100 mA
- Low diode capacitance: max. 1.5 pF
- Low diode forward resistance: max. 0.7 to 1.2Ω .

APPLICATION

Band-switching in VHF television tuners.

DESCRIPTION

Planar high performance band-switching diodes in a glass SOD80 SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _R	continuous reverse voltage	_	35	V
I _F	continuous forward current	_	100	mA
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	_	150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	I _F = 100 mA; see Fig.2	1.0	V
I _R	reverse current	see Fig.3		
		V _R = 20V	50	nA
		V _R = 20 V; T _j = 75 °C	1	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; see Fig.4	1.5	pF
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 3 \text{ V}$; see Fig.4		
	BA682		1.25	pF
	BA683		1.20	pF
r _D	diode forward resistance	I _F = 3 mA; f = 200 MHz; see Fig.5		
	BA682		0.7	Ω
	BA683		1.2	Ω
r _D	diode forward resistance	I _F = 10 mA; f = 200 MHz; see Fig.5		
	BA682		0.5	Ω
	BA683		0.9	Ω

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MBG307

T_j (°C) 150

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		300	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	600	K/W

10⁵

10⁴

10³

10²

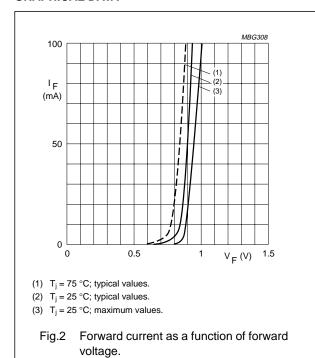
V_R = 20 V.

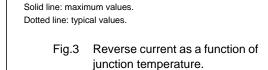
(nA)

Note

1. Device mounted on a FR4 printed-circuit board.

GRAPHICAL DATA

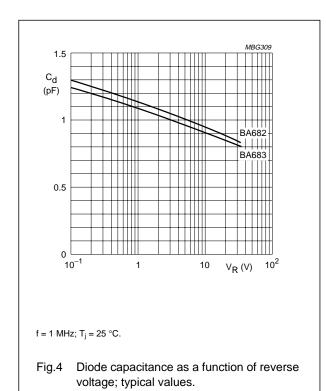




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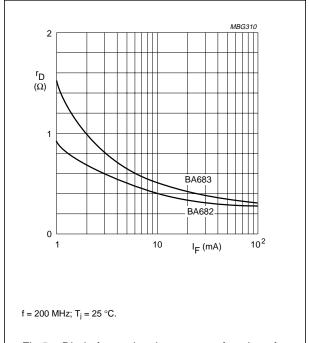


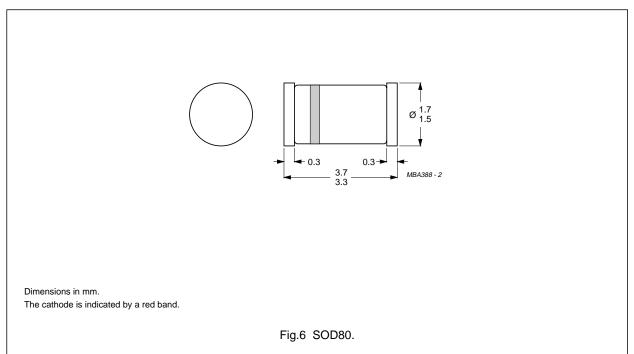
Fig.5 Diode forward resistance as a function of forward current; typical values.

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PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status				
Objective specification	Objective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.